

AUIPS7111S

CURRENT SENSE HIGH SIDE SWITCH

Features

- Suitable for 24V systems
- Over current shutdown
- Over temperature shutdown
- Current sensing
- Active clamp
- Low current
- Reverse battery
- ESD protection
- Optimized Turn On/Off for EMI

Applications

24V loads for trucks

Description

The AUIPS7111S is a fully protected four terminal high side switch. It features current sensing, over-current, over-temperature, ESD protection and drain to source active clamp. When the input voltage Vcc - Vin is higher than the specified threshold, the output power Mosfet is turned on. When the Vcc - Vin is lower than the specified Vil threshold, the output Mosfet is turned off. The Ifb pin is used for current sensing.

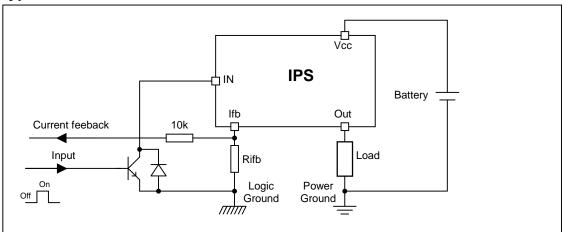
Product Summary

Rds(on) 7.5 m Ω max. Vclamp 65V Current shutdown 30A min.

Package



Typical Connection





Qualification Information[†]

addiniodion information							
			Automotive (per AEC-Q100 ^{††})				
Qualification Level		Comments: This family of ICs has passed an Automotive qualification IR's Industrial and Consumer qualification level is granted by extensio of the higher Automotive level.					
Moisture Sensitivity Level		D2PAK-5L	MSL1, 260°C (per IPC/JEDEC J-STD-020)				
	Machine Model		M3 (300V) C-Q100-003)				
ESD	Human Body Model		H2 (2,500 V) C-Q100-002)				
	Charged Device Model	Class (C4 (1000 V) C4 (1000 T) C-Q100-011)				
IC Latch-Up Te	est	Class II, Level A					
RoHS Complia		(per AE)	(per AEC-Q100-004) Yes				
compile	•••						

[†] Qualification standards can be found at International Rectifier's web site http://www.irf.com/

^{††} Exceptions to AEC-Q100 requirements are noted in the qualification report.



Absolute Maximum RatingsAbsolute maximum ratings indicate sustained limits beyond which damage to the device may occur. (Tj= -40°C..150°C,

Vcc=8..50V unless otherwise specified).

Symbol	Parameter	Min.	Max.	Units
Vout	Maximum output voltage	Vcc-60	Vcc+0.3	V
Vcc-Vin max.	Maximum Vcc voltage	-32	60	V
Ifb, max.	Maximum feedback current	-50	10	mΑ
Pd	Maximum power dissipation (internally limited by thermal protection)			W
Fu	Tambient=25°C, Tj=150°C Rth=50°C/W D²Pack 6cm² footprint		2.5	۷V
Tj max.	Max. storage & operating junction temperature	-40	150	°C

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Units
Rth1	Thermal resistance junction to ambient D ² Pak Std footprint	60	_	
Rth2	Thermal resistance junction to ambient D ² pak 6cm ² footprint	40	_	°C/W
Rth3	Thermal resistance junction to case D²pak	0.8	_	

Recommended Operating Conditions These values are given for a quick design.

Symbol	Parameter	Min.	Max.	Units
lout	Continuous output current, Tambient=85°C, Tj=125°C			۸
	Rth=40°C/W, D2pak 6cm2 footprint	_	10	_ A
Rifb		1.5	_	kΩ



Static Electrical Characteristics

Ti=-40...150°C, Vcc=8..50V (unless otherwise specified)

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
Vcc op.	Operating voltage range	8		50	V	
Rds(on)	ON state resistance Tj=25°C	_	6	7.5	mΩ	lds=10A
	ON state resistance Tj=150°C	_	12	15	11122	IUS=TOA
Icc off	Supply leakage current	_	2	6		Vin=Vcc=28V,Vifb=Vgnd
lout off	Output leakage current	_	2	6	μA	Vout=Vgnd, Tj=25°C
V clamp1	Vcc to Vout clamp voltage 1	60	65	_		Id=10mA
V clamp2	Vcc to Vout clamp voltage 2	_	66	_	V	Id=10A see fig. 2
Vih(2)	High level Input threshold voltage	_	5.5	6.8	V	Id=10mA
Vil(2)	Low level Input threshold voltage	3.5	5	_		
Rds(on) rev	Reverse On state resistance Tj=25°C	_	7	10	mΩ	Isd=10A,
	Reverse On state resistance Tj=150°C	_	13	18		Vcc-Vin=732V
Vf	Forward body diode voltage Tj=25°C	_	0.75	0.8	V	If=10A
	Forward body diode voltage Tj=125°C	_	0.6	0.65	٧	
Rin	Internal input resistor	180	250	350	Ω	Tj=-40°C125°C

⁽²⁾ Input thresholds are measured directly between the input pin and the tab. See also page 6

Switching Electrical Characteristics

Vcc=28V. Resistive load=3Ω. Ti=25°C

100 201, 1100,0110 1000 011, 1, 20 0							
Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions	
tdon	Turn on delay time to 20%	25	35	50	110		
tr	Rise time from 20% to 80% of Vcc	8	17	25	μs	See fig. 1	
tdoff	Turn off delay time	50	80	120	0	See lig. 1	
tf	Fall time from 80% to 20% of Vcc	5	13	35	μs		

Protection Characteristics

Ti=-40_150°C, Vcc=8_50V (unless otherwise specified)

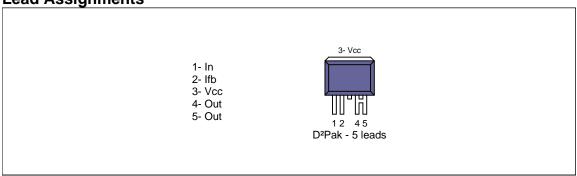
Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
Tsd	Over temperature threshold	150(3)	165	_	°C	See fig. 3 and fig. 10
Isd	Over-current shutdown	30	45	60	Α	See fig. 3 and page 7
I fault	Ifb after an over-current or an over-temperature (latched)	2.4	4	6	mA	See fig. 3

Current Sensing CharacteristicsTj=-40..150°C, Vcc=8..50V (unless otherwise specified)

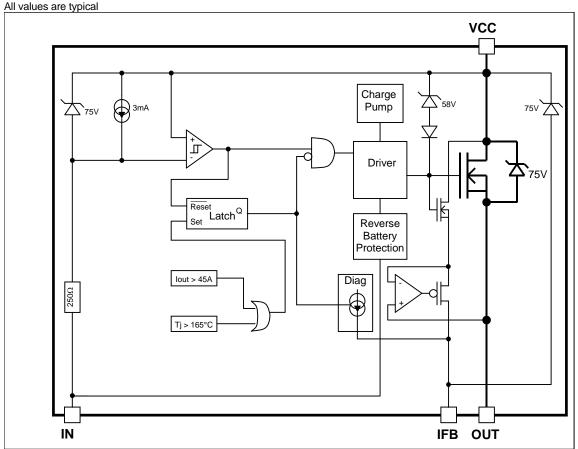
Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
Ratio	I load / Ifb current ratio	11000	13000	14500		lout=10A
Ratio_TC	I load / Ifb variation over temperature	-5%	0	+5	%	
I offset	Load current offset	-0.25	0	0.25	Α	lout<10A
Ifb leakage	Ifb leakage current on	0	6	15	μΑ	lout=0A, Tj=25°C

⁽³⁾ Guaranteed by design

Lead Assignments



Functional Block Diagram All values are typical





Truth Table

Op. Conditions	Input	Output	Ifb pin voltage
Normal mode	Н	L	0V
Normal mode	L	Н	I load x Rfb / Ratio
Open load	Н	L	0V
Open load	L	Н	Ifb leakage x Rifb
Short circuit to GND	Н	L	0V
Short circuit to GND	L	L	I fault x Rifb (latched)
Over temperature	Н	L	0V
Over temperature	L	L	I fault x Rifb (latched)

Operating voltage

Maximum Vcc voltage: this is the maximum voltage before the breakdown of the IC process.

Operating voltage: This is the Vcc range in which the functionality of the part is guaranteed. The AEC-Q100 qualification is run at the maximum operating voltage specified in the datasheet.

Reverse battery

During the reverse battery the Mosfet is turned on if the input pin is powered with a diode in parallel of the input transistor. Power dissipation in the IPS: $P = Rdson rev * I load^2 + Vcc^2 / 250$ (internal input resistor).

If the power dissipation I too hight in Rifb, a diode in serial can be added to block the current.

Active clamp

The purpose of the active clamp is to limit the voltage across the MOSFET to a value below the body diode break down voltage to reduce the amount of stress on the device during switching.

The temperature increase during active clamp can be estimated as follows:

$$\Delta_{\mathsf{Tj}} = \mathsf{P}_{\mathsf{CL}} \cdot \mathsf{Z}_{\mathsf{TH}}(\mathsf{t}_{\mathsf{CLAMP}})$$

Where: $Z_{TH}(t_{CLAMP})$ is the thermal impedance at t_{CLAMP} and can be read from the thermal impedance curves given in the data sheets.

 $P_{CL} = V_{CL} \cdot I_{CLavg}$: Power dissipation during active clamp

 $V_{\scriptscriptstyle CL} = 39 V$: Typical $V_{\scriptscriptstyle CLAMP}$ value

 $I_{CLavg} = \frac{I_{CL}}{2}$: Average current during active clamp

 $t_{\text{CL}} = \frac{I_{\text{CL}}}{\left|\frac{di}{dt}\right|} : \text{Active clamp duration}$

 $\frac{di}{dt} = \frac{V_{\text{Battery}} - V_{\text{CL}}}{L} : \text{Demagnetization current}$

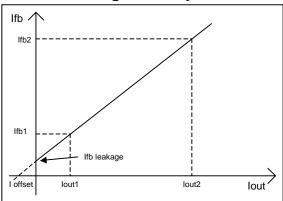
Figure 9 gives the maximum inductance versus the load current in the worst case : the part switch off after an over temperature detection. If the load inductance exceed the curve, a free wheeling diode is required.



Input level VIH/VIL

The input level are referenced to Vcc. When Vcc-Vin exceed VIH the part turns on and when Vcc-Vin goes below VIL the part turns off

Current sensing accuracy



The current sensing is specified by measuring 3 points :

- Ifb1 for lout1
- Ifb2 for lout2
- Ifb leakage for lout=0

The parameters in the datasheet are computed with the following formula:

Ratio = (lout2 - lout1)/(lfb2 - lfb1)

I offset = Ifb1 x Ratio - Iout1

This allows the designer to evaluate the lfb for any lout value using :

Ifb = (lout + I offset) / Ratio if Ifb > Ifb leakage

For some applications, a calibration is required. In that case, the accuracy of the system will depends on the variation of the I offset and the ratio over the temperature range. The ratio variation is given by Ratio_TC specified in page 4.

The loffset variation depends directly of the Rdson:

I offset@-40°C= I offset@25°C / 0.7

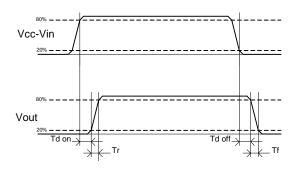
I offset@150°C= I offset@25°C / 1.9

Over-current protection

The threshold of the over-current protection is set in order to guaranteed that the device is able to turn on a load with an inrush current lower than the minimum of lsd. Nevertheless for high current and high temperature the device may switch off for a lower current due to the over-temperature protection (see Figure 10).

AUIPS7111S





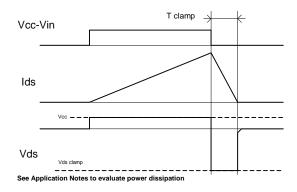


Figure 1 – IN rise time & switching definitions

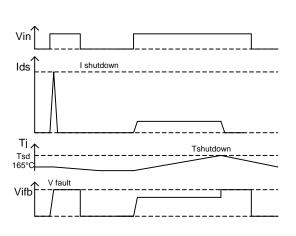


Figure 3 - Protection timing diagram

Figure 2 - Active clamp waveforms

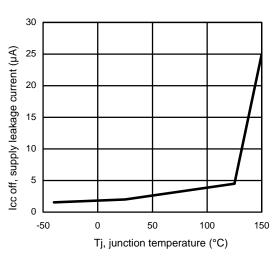


Figure 4 – Icc off (µA) Vs Tj (°C)

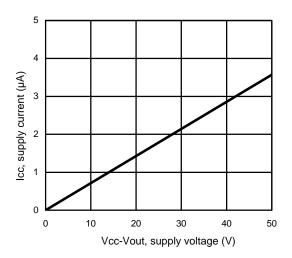


Figure 5 – Icc Off(µA) Vs Vcc-Vout (V)

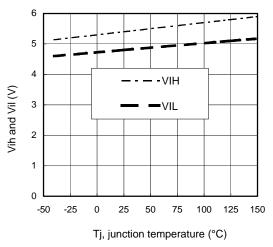


Figure 6 - Vih and Vil (V) Vs Tj (°C)

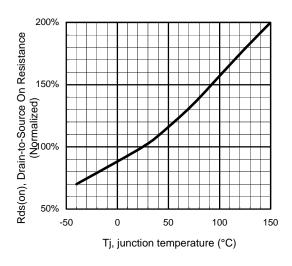


Figure 7 - Normalized Rds(on) (%) Vs Tj (°C)

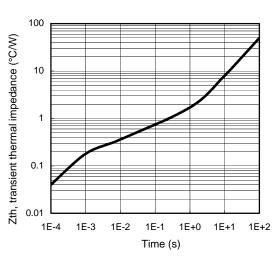
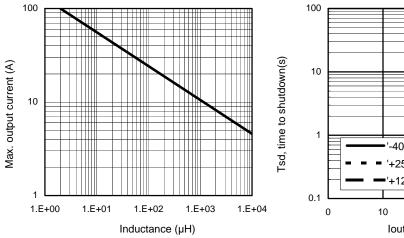


Figure 8 – Transient thermal impedance (°C/W) Vs time (s)





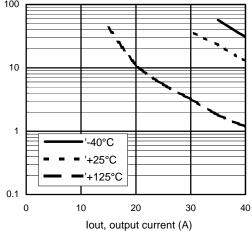
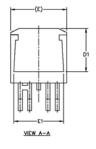


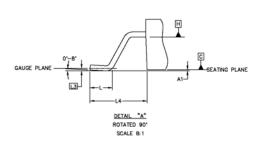
Figure 9 - Max. lout (A) Vs inductance (µH)

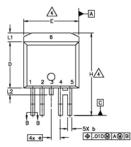
Figure 10 – Tsd (s) Vs I out (A) SMD with 6cm²

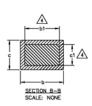


Case Outline D2PAK - 5 Leads

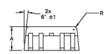


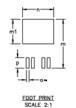


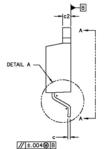




ŭ			N		
M B O L	MILLIM	ETERS	INC	HES	O T
Ĺ	MIN.	MAX.	MIN.	MAX.	Š
Α	4.06	4.83	.160	.190	
A1		0.254		.010	
ь	0.66	0.91	.026	.036	4
ь1	0.66	0.81	.026	.032	
c	0.38	0.74	.015	.029	
c1	0.38	0.58	.015	.023	4
c2	1.14	1.65	.045	.065	
D	8.51	9.65	.335	.380	3
D1	6.86		.270		
Ε	9.65	10.67	.380	.420	3
E1	6.22		.245		
е	1.70 BSC		.067 BSC		
н	14.73	15.49	.580	.609	
L	1.14	1.39	.045	.055	
L1		1.65		.065	
L2	1.27	1.78	.050	.070	
L3	0.25	BSC	.010	BSC	
L4	4.78	5.28	.188	.208	
m	17.78		.700		
m1	8.89		.350		
n	11.43		.450		
٥	1.93		.076		
р	3.81		.150		
R	0.51	0.71	.020	.028	







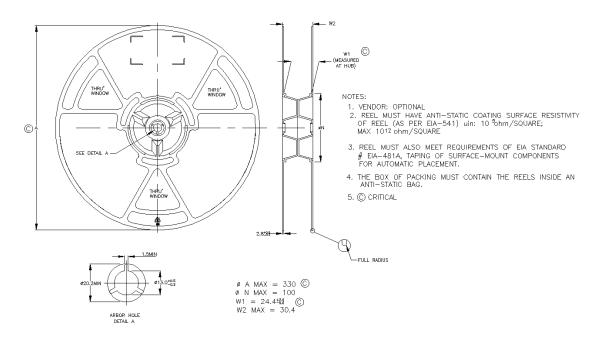
NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994
- 2. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].
- 3. DIMENSION D & E DO NOT INCLUDE MOLD FLASH, MOLD FLASH SHALL NOT EXCEED 0.127 [.005"] PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY.

4. DIMENSION 61 AND 61 APPLY TO BASE METAL ONLY.

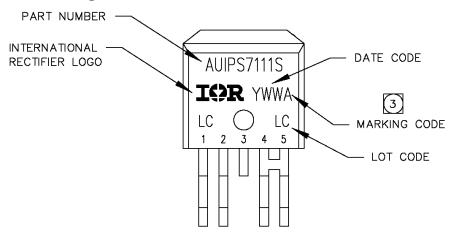
- 5. CONTROLLING DIMENSION: MILLIMETERS
- 6. LEADS AND DRAIN ARE PLTED WITH 100% Sn

Tape & Reel D2PAK - 5 Leads





Part Marking Information



Ordering Information

Base Part Number	Barbara Tarra	Standard Pack	Commiste Bort Number	
base i ait ivuilibei	Package Type	Form	Quantity	Complete Part Number
		Tube	50	AUIPS7111S
AUIPS7111R D2-Pak-5-Leads		Tape and reel left	800	AUIPS7111STRL
		Tape and reel right	800	AUIPS7111STRR



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